

PCN# 20240429005.1 Qualification of RFAB using qualified Process Technology, Die Revision, Datasheet, and additional Assembly site/BOM options for select devices Change Notification / Sample Request

Date: April 30, 2024 To: PREMIER FARNELL PCN

Dear Customer:

This is an announcement of a change to a device that is currently offered by Texas Instruments (TI). The details of this change are on the following pages, and are in alignment with our standard product change notification (PCN) <u>process</u>.

TI requires acknowledgement of receipt of this notification within 30 days of the date of this notice. Lack of acknowledgement of this notice within 30 days constitutes acceptance and approval of this change. If samples or additional data are required, requests must be received within 30 days of this notification, given that samples are not built ahead of the change.

The Proposed First Ship date in this PCN letter is the earliest possible date that customers could receive the changed material. It is our commitment that the changed device will not ship before that date. If samples are requested within the 30 day sample request window, customers will still have 30-days to complete their evaluation regardless of the proposed 1st ship date.

This particular PCN is related to TI's multiyear transition plan for our two remaining factories with 150-millimeter production (DFAB in Dallas, Texas, and SFAB in Sherman, Texas). DFAB will remain open, but will focus on 200-mm production, with a smaller set of technologies. SFAB will close no earlier than 2024 and no later than 2025. As referenced in the "reason for change" below, these changes are part of our multiyear plan to transition these products to newer, more efficient manufacturing processes and technologies, underscoring our commitment to product longevity and supply continuity.

For questions regarding this notice or to provide acknowledgement of this PCN, you may contact your local Field Sales Representative or the Change Management team. For sample requests or sample related questions, contact your local Field Sales Representative. As always, we thank you for your continued business.

Change Management Team SC Business Services

20240429005.1 Attachment: 1

Products Affected:

The devices listed on this page are a subset of the complete list of affected devices. According to our records, you have recently purchased these devices. The corresponding customer part number is also listed, if available.

DEVICE	CUSTOMER PART NUMBER
SN75174N	NULL

Technical details of this Product Change follow on the next page(s).

CN Numbe		20240429005			PCN D			30, 2024
		of RFAB using						
		nd additional A			· ·	for sel		
ustomer C	Contact:	Change M	anagement	_	Dept:		Quali	ty Services
•	st Ship Dat			acce	le reqເ epted ເ	intil:		30, 2024*
		eived after M	lay 30, 202	24 will n	ot be s	suppo	rted.	
nange Typ						_		
Assemb			Design					mp Material
2	ly Process		Data Sheet			=		mp Process
	ly Materials		Part numbe	r change			fer Fal	
2	ical Specific		Test Site			-		o Material
Packing	/Shipping/L	abeling	Test Proces				ter Fal	o Process
			PCN Det	ails				
	of Change							
additiona	l Wafer Fab	eased to annou option in addit						
ted below.					A .1 .1 .		E-h C	
		Fab Site				ional		
Current Fa Site	b Proce	ss Wafer D	nameter	Additio		Proc	ess	Wafer
SFAB	JI1	150	mm	Fab Si	te			Diameter
SFAD			mm					
SEVB	1 () 1							
SFAB				REAR		I BC	~7	300 mm
SFAB	IMPC6	0 150	mm	RFAE	3	LBC	7	300 mm
	IMPC6 LBC2	0 150 150	mm mm	RFAE	3	LBC	27	300 mm
SFAB DFAB DFAB ne die was	IMPC6 LBC2 LBC3 also change	0 150 150	mm mm / 200mm of the proces			LBC	27	300 mm
SFAB DFAB DFAB ne die was onstruction roup 1 De	IMPC6 LBC2 LBC3 also change differences vice: No m	0 150 2 150 S 150mm / ad as a result of are as follows aterial chang	mm mm / 200mm of the proces :: je	ss change		LBC	.7	300 mm
SFAB DFAB DFAB ne die was onstruction roup 1 De	IMPC6 LBC2 LBC3 also change differences vice: No m	0 150 2 150 S 150mm / Sd as a result of are as follows are as follows aterial chang aterial differen aterial differen	mm mm / 200mm of the proces :: je	ss chango n sites	e.	LBC	.7	300 mm
SFAB DFAB DFAB ne die was onstruction roup 1 De roup 2 De	IMPC6 LBC2 LBC3 also change differences vice: No m vice: No m	0 150 2 150 S 150mm / ed as a result of are as follows aterial change aterial differen Current	mm mm / 200mm of the proces :: je	ss chango n sites Propos o	e.		.7	300 mm
SFAB DFAB DFAB ne die was onstruction roup 1 De roup 2 De Asser	IMPC6 LBC2 LBC3 also change differences vice: No m vice: No m nbly site	0 150 2 150 S 150mm / ad as a result of are as follows aterial change aterial differen Current MLA	mm mm / 200mm of the proces :: ge ces betwee	ss chango n sites Proposo FMX	e.		.7	300 mm
SFAB DFAB DFAB ne die was onstruction roup 1 De roup 2 De Asser	IMPC6 LBC2 LBC3 also change differences vice: No m vice: No m nbly site	0 150 2 150 S 150mm / ad as a result of are as follows aterial change aterial differen Current MLA aterial differen MLA	mm mm / 200mm of the proces :: ge ces betwee	ss change n sites Propose FMX n sites	e. ed		.7	300 mm
SFAB DFAB DFAB ne die was onstruction roup 1 De roup 2 De Asser	IMPC6 LBC2 LBC3 also change differences vice: No m vice: No m nbly site	0 150 2 150 S 150mm / ad as a result of are as follows aterial change aterial differen Current MLA aterial differen Current MLA	mm mm / 200mm of the proces :: ge ces betwee	ss chango n sites Proposo FMX n sites Proposo	e. ed		.7	300 mm
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SFAB DFAB DFAB ne die was onstruction roup 1 De roup 2 De Asser roup 3 De Asser	IMPC6 LBC3 LBC3 also change differences vice: No m vice: No m nbly site vice: No m nbly site	0 150 2 150 S 150mm / ad as a result of are as follows aterial chang aterial differen MLA aterial differen MLA aterial differen MLA aterial differen MLA	mm mm / 200mm of the proces :: ge ces betwee ces betwee	ss change n sites Propose FMX n sites Propose CDAT n sites Propose	ed ed			300 mm
SFAB DFAB DFAB ne die was onstruction roup 1 De roup 2 De Asser roup 3 De Asser	IMPC6 LBC3 LBC3 also change differences vice: No m vice: No m nbly site vice: No m	0 150 2 150 S 150mm / ad as a result of are as follows aterial change aterial differen MLA aterial differen MLA aterial differen MLA	mm mm / 200mm of the proces :: ge ces betwee ces betwee	n sites Propose FMX n sites Propose CDAT n sites	ed ed			300 mm
SFAB DFAB DFAB ne die was onstruction roup 1 De roup 2 De Asser roup 3 De Asser	IMPC6 LBC3 also change differences vice: No m vice: No m nbly site vice: No m nbly site vice: No m	0 150 2 150 S 150mm / ad as a result of are as follows aterial chang aterial differen MLA aterial differen MLA aterial differen MLA aterial differen MLA	mm mm / 200mm of the proces :: ge ces betwee ces betwee	ss change n sites Propose FMX n sites Propose CDAT n sites Propose	ed ed			300 mm
SFAB DFAB DFAB ne die was onstruction roup 1 De roup 2 De Asser roup 3 De Asser	IMPC6 LBC3 also change differences vice: No m vice: No m nbly site vice: No m nbly site vice: No m	0 150 2 150 S 150mm / ad as a result of are as follows aterial chang aterial differen MLA aterial differen MLA aterial differen MLA aterial differen MLA	mm mm / 200mm of the proces :: ge ces betwee ces betwee	ss change n sites Propose FMX n sites Propose CDAT n sites Propose	ed ed			300 mm
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SFAB DFAB DFAB DFAB ne die was onstruction roup 1 De roup 2 De Asser roup 3 De Asser roup 4 De Asser roup 5 De	IMPC6 LBC2 LBC3 also change differences vice: No m vice: No m nbly site vice: No m nbly site vice: No m nbly site vice: No m	0 150 2 150 S 150mm / ed as a result of are as follows aterial change aterial differen Current MLA aterial differen Current MLA aterial differen Current MLA aterial differen Current MLA aterial differen Current TAI 4042500 4205694	mm mm / 200mm of the proces :: ge ces betwee ces betwee	ss change ropose FMX n sites Propose CDAT n sites Propose MLA MLA 414785 421188	e. ed ed ed			300 mm

TEXAS INSTRUMENTS

SLLS038C - OCTOBER 1980 - REVISED APRIL 2024

С	hanges from Revision B (May 1995) to Revision C (April 2024)	Page
•	Changed the numbering format for tables, figures, and cross-references throughout the document	1
•	Added the Thermal Information table	5
•	Changed Note A in Figure 6-2 and Figure 6-3	<mark>8</mark>

	TEXAS INSTRUMENTS	SN75174 SLLS039C – OCTOBER 1980 – REVISED APRIL 2024
С	hanges from Revision B (May 1995) to Revision C (April 2024)	Page
•	Changed the numbering format for tables, figures, and cross-refere	nces throughout the document1
•	Added the Thermal Information table	5
•	Changed Note A in Figure 6-3	9

TEXAS INSTRUMENTS	SILS121E – AUGUST 1990 – REVISED APRIL 2024
Changes from Povision D (April 4009) to Povision	E (April 2024) Dage
Changes from Revision D (April 1998) to Revision	E (April 2024) Page
	and cross-references throughout the document
Changed the numbering format for tables, figures,	

TEXAS INSTRUMENTS	SN75ALS174A SLLS122G – JULY 1991 – REVISED APRIL 2024
Changes from Revision F (January 2018) to Revision G (April 20	24) Page
 Changed the numbering format for tables, figures, and cross-reference. Added the <i>Thermal Information</i> table. Changed Note A in Figure 6-3 	

TEXAS INSTRUMENTS	SN65LBC174, SN75LBC174 SLLS162F – JULY 1993 – REVISED APRIL 2024
Changes from Revision E (April 2006) to Revision F (April 2024)	Page
Changed the numbering format for tables, figures, and cross-refere	ences throughout the document1
Added the Thermal Information table	
Changed the t _{t(OD)} MIN value from 10ns to 9ns in the Switching Ch	aracteristics 7

V INSTRUMENTS	SN65LBC172, SN75LBC17 SLLS163F – JULY 1993 – REVISED APRIL 20
Changes from Revision E (April 2006) to Revision F (April 20	024) Page
· Changed the numbering format for tables, figures, and cross-	references throughout the document 1
Added the Thermal Information table	
TEXAS	SN65LBC174A, SN75LBC174

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	vision F (October			Page
			d cross-references throughout the document	
Texas Instrument	TS		SN65LBC172A, SN75 SLLS447D – OCTOBER 2000 – REVISED	
Changes from Rev	ision C (August 2	2008) to Revision		Page
Changed the nu	mbering format for	tables, figures, an	d cross-references throughout the document	
TEXAS INSTRUMENT	ſS		AN SLLS848C – APRIL 2008 – REVISED	APRIL 202
hanges from Rev	ision B (Septemb	er 2016) to Revis	ion C (April 2024)	Pag
-			Information table	
Changed the not	e in Figure 6-3			
	vision * (June 2023		SLLSFU5A – JUNE 2023 – REVISEI	Page
INSTRUMENT Changes from Rev Changed the Th	vision * (June 2023 Dermal Information t	table	SLLSFU5A – JUNE 2023 – REVISE	Page
INSTRUMEN Changes from Rev Changed the Th Changed Note A	vision * (June 2023 Dermal Information t	table	SLLSFU5A – JUNE 2023 – REVISEI	Page
INSTRUMENT Changes from Rev Changed the Th	vision * (June 2023 permal Information t A in Figure 6-4	table	SLLSFU5A – JUNE 2023 – REVISEI	Page
Changes from Rev Changed the Th Changed Note A Product	vision * (June 2023 nermal Information t A in Figure 6-4 Current Datasheet	New Datasheet	SLLSFU5A – JUNE 2023 – REVISEI	Page
Changes from Rev Changed the Th Changed Note A Product Folder	vision * (June 2023 nermal Information to A in Figure 6-4 Current Datasheet Number	New Datasheet Number	SLLSFU5A – JUNE 2023 – REVISE	2 <u>2</u>
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INSTRUMEN Changes from Rev Changed the Th Changed Note A Product Folder SN75172 SN75174 SN75174 SN75ALS172A SN75ALS174A SN65LBC174, SN75LBC174 SN65LBC172,	vision * (June 2023 nermal Information to A in Figure 6-4 Datasheet Number SLLS038B SLLS039B SLLS121D SLLS122F	New Datasheet Number SLLS038C SLLS039C SLLS121E SLLS122G SLLS162F SLLS163F	SLLSFU5A – JUNE 2023 – REVISEI April 2024) Link to full datasheet http://www.ti.com/product/SN7517 http://www.ti.com/product/SN7517 http://www.ti.com/product/SN75AL http://www.ti.com/product/SN75AL	2 <u>2</u> <u>4</u> <u>5172A</u> <u>5174A</u> <u>C174</u>
INSTRUMEN Changes from Rev Changed the Th Changed Note A Product Folder SN75172 SN75174 SN75ALS172A SN75ALS172A SN75LBC174 SN65LBC172, SN75LBC172	vision * (June 2023 nermal Information to A in Figure 6-4 Datasheet Number SLLS038B SLLS039B SLLS121D SLLS122F SLLS162E	New Datasheet Number SLLS038C SLLS039C SLLS121E SLLS122G SLLS162F	April 2024) Link to full datasheet http://www.ti.com/product/SN7517 http://www.ti.com/product/SN7517 http://www.ti.com/product/SN75AL http://www.ti.com/product/SN75AL	2 <u>2</u> <u>4</u> <u>5172A</u> <u>5174A</u> <u>C174</u> <u>C172</u>
Changes from Rev Changed the Th Changed the Th Changed Note A Product Folder SN75172 SN75172 SN75174 SN75ALS172A SN75ALS174A SN65LBC174A SN65LBC172, SN75LBC172 SN75LBC172A, N65LBC172A,	vision * (June 2023 nermal Information to A in Figure 6-4 Datasheet Number SLLS038B SLLS039B SLLS121D SLLS122F SLLS162E SLLS163E	New Datasheet Number SLLS038C SLLS039C SLLS121E SLLS122G SLLS162F SLLS163F	April 2024) Link to full datasheet http://www.ti.com/product/SN7517 http://www.ti.com/product/SN7517 http://www.ti.com/product/SN75AL http://www.ti.com/product/SN75AL http://www.ti.com/product/SN65LB http://www.ti.com/product/SN65LB	2 <u>2</u> <u>4</u> <u>5172A</u> <u>5172A</u> <u>5174A</u> <u>C174</u> <u>C172</u> <u>C174A</u>
INSTRUMEN Changes from Rev Changed the Th Changed Note A Product Folder SN75172	Current Datasheet Number SLLS038B SLLS121D SLLS122F SLLS162E SLLS446F	New Datasheet Number SLLS038C SLLS039C SLLS121E SLLS122G SLLS162F SLLS163F SLLS163F	SLLSFU5A – JUNE 2023 – REVISEI April 2024) Link to full datasheet http://www.ti.com/product/SN7517 http://www.ti.com/product/SN7517 http://www.ti.com/product/SN7517 http://www.ti.com/product/SN7517 http://www.ti.com/product/SN75AL http://www.ti.com/product/SN75AL http://www.ti.com/product/SN65LB http://www.ti.com/product/SN65LB http://www.ti.com/product/SN65LB	2 <u>2</u> <u>4</u> <u>5172A</u> <u>5174A</u> <u>6</u> <u>774A</u> <u>6</u> <u>774A</u> <u>6</u> <u>774A</u> <u>6</u> <u>774A</u> <u>6</u> <u>774A</u> <u>772A</u> <u>772A</u>

Qual details are provided in the Qual Data Section.

Reason for Change:

These changes are part of our multiyear plan to transition products from our 150-millimeter factories to newer, more efficient manufacturing processes and technologies, underscoring our commitment to product longevity and supply continuity.

Anticipated impact on Form, Fit, Function, Quality or Reliability (positive / negative):

None

Impact on Environmental Ratings:

Checked boxes indicate the status of environmental ratings following implementation of this change. If below boxes are checked, there are no changes to the associated environmental ratings.

RoHS	REACH	Green Status	IEC 62474			
🛛 🛛 No Change	🛛 No Change	🛛 🛛 No Change	🔀 No Change			
Changes to product i	Changes to product identification resulting from this PCN:					
Fab Site Information:						
Chip Site	Chip Site Origin Code (20L)	Chip Site Country Code (21L)	Chip Site City			
SH-BIP-1	SHE	USA	Sherman			
DL-LIN	DLN	USA	Dallas			
RFAB	RFB	USA	Richardson			

Die Rev:

Current	New
Die Rev [2P]	Die Rev [2P]
A, B, C,-	-

Assembly Site Information:

Assembly Site	Assembly Site Origin (22L)	Assembly Country Code (23L)	Assembly City
TAI	TAI	TWN	Chung Ho, New Taipei City
CDAT	CDA	CHN	Chengdu
MLA	MLA	MYS	Kuala Lumpur
FMX	MEX	MEX	Aguascalientes

Sample product shipping label (not actual product label):



Product Affected:							
Group 1 Device: Wa	afer fab, Design, Data	sheet					
AM26LV31EINSR	AM26LV31INSR	SN65LBC174A16DWR	SN75174N				
	·	·					

AM26LV31EIPWR	SN65LBC172A16DWR	SN65LBC174A16DWR	G4 SN75174NE4					
AM26LV31EIPWRG4	SN65LBC172AN	SN65LBC174AN	SN65LBC172ADWR					
AM26LV31IDR	AM26LV31IDR SN65LBC172ANE4							
Group 2 Device: Wafer fab, Design, Data sheet, Assembly site								
AM26LV31EIDR	AM26LV31EIDRG4							
Group 3 Device: Wafer fab, Design, Data sheet, Assembly site								
AM26LV31EIRGYR	AM26LV31EIRGYRG4	1						
Group 4 Device: Wa	fer fab, Design, Data	sheet, Assembly s	ite					
SN75ALS174ADWR	SN75174DWR	SN75174DWRE4	SN75172DWR					
Group 5 Device: Wafer fab, Design, Data sheet, Assembly site, BOM								
SN65LBC174ADWR	SN75LBC172DWR	SN75ALS172ADW	/R					
SN65LBC174DWR	SN75ALS174DWR							

For alternate parts with similar or improved performance, please visit the product page on TI.com

Qualification Results

						Dat	a Displayed a	s: Number (of lots / Tot	al sample size	Total failed					
Туре	#	Test Name	Condition	Duration	Qual Device: SN65LBC172ADWR	Qual Device: SN65LBC174ADWR	Qual Device: <u>SN65LBC174DWR</u>	Qual Device: SN75172DWR	Qual Device: <u>SN75174DWR</u>	Qual Device: <u>SN75ALS172ADWR</u>	Qual Device: SN75ALS174ADWR	Qual Device: <u>SN75ALS174DWR</u>	Qual Device: <u>SN75LBC172DWR</u>	QBS Reference (Package): ULN2803CDWR	QBS Reference (Package): <u>SN74HCS244QPWRQ1</u>	QBS Reference (Product): AM26LV31EIDR
HAST	A2	Biased HAST	130C/85%RH	96 Hours											1/77/0	
UHAST	A3	Autoclave	121C/15psig	96 Hours	-	-		•		-	-				3/231/0	
тс	A4	Temperature Cycle	-65C/150C	500 Cycles	-	-	-	-	-	-	-	-	-	1/77/0	1/77/0	
HTSL	A6	High Temperature Storage Life	150C	1000 Hours	-	-		-	-	-	-	-	-	-	1/45/0	
WBS	C1	Ball Shear	76 balls, 3 units min	Wires	1/76/0	1/76/0	1/76/0	1/76/0	1/76/0	1/76/0	1/76/0	1/76/0	1/76/0	-	-	
WBP	C2	Bond Pull	76 Wires, 3 units min	Wires	1/76/0	1/76/0	1/76/0	1/76/0	1/76/0	1/76/0	1/76/0	1/76/0	1/76/0			
ESD	E2	ESD CDM		1000 Volts	1/3/0	1/3/0						-				1/3/0
ESD	E2	ESD HBM (Bus Pins)		12000 Volts	1/3/0	1/3/0		-	-	-	-	-		-	-	
ESD	E2	ESD HBM		2000 Volts					-			-				1/3/0
ESD	E2	ESD HBM		4000 Volts			1/3/0			1/3/0	1/3/0	1/3/0	1/3/0			
ESD	E2	ESD HBM		5000 Volts	1/3/0	1/3/0	-	-	-	-	-	-	-	-		
LU	E4	Latch-Up	Per JESD78	•	1/6/0	1/6/0	1/6/0			1/6/0	1/6/0	1/6/0	1/6/0		1/6/0	1/6/0
CHAR	E5	Electrical Characterization	Per Datasheet Parameters	-	1/30/0	1/30/0	1/30/0	1/30/0	1/30/0	1/30/0	1/30/0	1/30/0	1/30/0	1/30/0	-	1/30/0

QBS: Qual By Similarity
 Qual Device SN65LBC172ADWR is qualified at MSL1 260C
 Qual Device SN65LBC174DWR is qualified at MSL1 260C
 Qual Device SN7512CWR is qualified at MSL1 260C
 Qual Device SN75172WR is qualified at MSL1 260C
 Qual Device SN7514DWR is qualified at MSL1 260C
 Qual Device SN754LS174DWR is qualified at MSL1 260C

Preconditioning was performed for Autoclave, Unbiased HAST, THB/Blased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable
 The following are equivalent HTOL options based on an activation energy of 0.7eV : 152C/L Hours, 140/C480 hours, 150C/300 Hours, and 155C/240 Hours
 The following are equivalent HTSL options based on an activation energy of 0.7eV : 150C/L Hours, and 170C/420 Hours,
 The following are equivalent HTSL options based on an activation energy of 0.7eV : 150C/L Hours, and 170C/420 Hours,
 The following are equivalent Temp Cycle options per JESD47 :-55C/L25C/700 Cycles and -65C/L50C/500 Cycles

Quality and Environmental data is available at TI's external Web site: http://www.ti.com/

TI Qualification ID: R-CHG-2206-018

Qualification Results

Data Displayed as: Number of lots / Total sample size / Total failed

Туре	#	Test Name	Condition	Duration	Qual Device: <u>AM26LV31IDR</u>	QBS Reference (Package): <u>TCA9546ADR</u>	QBS Reference (Package): <u>TL494IDR</u>	QBS Reference (Process): <u>AM26LV31EIDR</u>
HAST	A2	Biased HAST	130C/85%RH	96 Hours	-	-	3/231/0	-
UHAST	A3	Unbiased HAST	130C/85%RH	96 Hours	-	3/231/0	-	-
тс	A4	Temperature Cycle	-65C/150C	500 Cycles	-	3/231/0	-	-
HTSL	A6	High Temperature Storage Life	150C	1000 Hours	-	3/231/0	-	-
WBS	C1	Ball Shear	76 balls, 3 units min	Wires	-	-	-	1/76/0
WBP	C2	Bond Pull	76 Wires, 3 units min	Wires	-	-	-	1/76/0
SD	C3	PB-Free Solderability	Precondition w.155C Dry Bake (4 hrs +/- 15 minutes); PB-Free Solder;	-	-	3/66/0	-	-
ESD	E2	ESD CDM	-	250 Volts	1/3/0	-	-	1/3/0
ESD	E2	ESD HBM	-	1000 Volts	1/3/0	-	-	-
LU	E4	Latch-Up	Per JESD78	-	1/3/0	-	-	-
CHAR	E5	Electrical Characterization	Per Datasheet Parameters	-	1/30/0	-	-	-

QBS: Qual By Similarity

Qual Device AM26LV31IDR is qualified at MSL1 260C

Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable

• The following are equivalent HTOL options based on an activation energy of 0.7eV : 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours

• The following are equivalent HTSL options based on an activation energy of 0.7eV : 150C/1k Hours, and 170C/420 Hours

• The following are equivalent Temp Cycle options per JESD47 : -55C/125C/700 Cycles and -65C/150C/500 Cycles

Quality and Environmental data is available at TI's external Web site: http://www.ti.com/

TI Qualification ID: R-CHG-2212-024

Qualification Results

Data Displayed as: Number of lots / Total sample size / Total failed

Туре	#	Test Name	Condition	Duration	Qual Device: <u>SN65LBC172AN</u>	Qual Device: <u>SN65LBC174AN</u>	Qual Device: <u>SN75172N</u>	Qual Device: <u>SN75174N</u>	QBS Reference (Package): <u>MSP430F2013IN</u>	QBS Reference (Process, Product): <u>SN74HCS74QPWRQ1</u>
UHAST	A3	Autoclave	121C/15psig	96 Hours	-	-	-	-	3/231/0	-
тс	A4	Temperature Cycle	-65C/150C	500 Cycles	-	-	-	-	3/231/0	-
HTSL	A6	High Temperature Storage Life	170C	420 Hours	-	-	-	-	3/231/0	-
HTOL	B1	Life Test	125C	1000 Hours	-	-	-	-	-	3/231/0
ELFR	B2	Early Life Failure Rate	125C	48 Hours	-	-	-	-	-	3/2400/0
WBS	C1	Ball Shear	76 balls, 3 units min	Wires	1/76/0	1/76/0	1/76/0	1/76/0	-	-
WBP	C2	Bond Pull	76 Wires, 3 units min	Wires	1/76/0	1/76/0	1/76/0	1/76/0	-	-
SD	C3	PB-Free Solderability	8 Hours Steam Age	-	-	-	-	-	3/66/0	-
ESD	E2	ESD CDM	-	1000 Volts	1/3/0	-	1/3/0	-	-	-

Туре	#	Test Name	Condition	Duration	Qual Device: <u>SN65LBC172AN</u>	Qual Device: <u>SN65LBC174AN</u>	Qual Device: <u>SN75172N</u>	Qual Device: <u>SN75174N</u>	QBS Reference (Package): <u>MSP430F2013IN</u>	QBS Reference (Process, Product): <u>SN74HCS74QPWRQ1</u>
ESD	E2	ESD HBM (Bus Pins)	-	12000 Volts	1/3/0	1/3/0	-	-	-	-
ESD	E2	ESD HBM	-	2000 Volts	-	-	1/3/0	1/3/0	-	1/3/0
ESD	E2	ESD HBM	-	5000 Volts	1/3/0	1/3/0	-	-	-	-
LU	E4	Latch-Up	Per JESD78	-	1/6/0	1/6/0	1/6/0	1/6/0	-	-
CHAR	E5	Electrical Characterization	Per Datasheet Parameters	-	1/30/0	1/30/0	1/30/0	1/30/0	-	-

• QBS: Qual By Similarity

Qual Device SN65LBC172AN is qualified at NOT CLASSIFIED NOT CLASSIFIED

Qual Device SN65LBC174AN is qualified at NOT CLASSIFIED NOT CLASSIFIED

Qual Device SN75172N is qualified at NOT CLASSIFIED NOT CLASSIFIED

Qual Device SN75174N is qualified at NOT CLASSIFIED NOT CLASSIFIED

Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable

• The following are equivalent HTOL options based on an activation energy of 0.7eV : 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours

• The following are equivalent HTSL options based on an activation energy of 0.7eV : 150C/1k Hours, and 170C/420 Hours

The following are equivalent Temp Cycle options per JESD47 : -55C/125C/700 Cycles and -65C/150C/500 Cycles

Quality and Environmental data is available at TI's external Web site: http://www.ti.com/

TI Qualification ID: R-CHG-2205-045

Qualification Results

Data Displayed as: Number of lots / Total sample size / Total failed

Туре	#	Test Name	Condition	Duration	Qual Device: <u>AM26LV31EINSR</u>	Qual Device: <u>AM26LV31INSR</u>	QBS Reference (Package): <u>SN74LVC8T245NSR</u>	QBS Reference (Product): <u>AM26LV31EIDR</u>
тс	A4	Temperature Cycle	-65C/150C	500 Cycles	-	-	3/231/0	-
HTSL	A6	High Temperature Storage Life	150C	1000 Hours	-	-	3/231/0	-
WBS	C1	Ball Shear	76 balls, 3 units min	Wires	1/76/0	1/76/0	-	-
WBP	C2	Bond Pull	76 Wires, 3 units min	Wires	1/76/0	1/76/0	-	-
ESD	E2	ESD CDM	-	250 Volts	-	1/3/0	-	-
ESD	E2	ESD HBM	-	1000 Volts	1/3/0	-	-	1/3/0
ESD	E2	ESD HBM (Bus Pins)	-	15000 Volts	1/3/0	-	-	1/3/0
LU	E4	Latch-Up	Per JESD78	-	-	-	-	1/6/0
CHAR	E5	Electrical Characterization	Per Datasheet Parameters	-	1/30/0	1/30/0	-	1/30/0

• QBS: Qual By Similarity

Qual Device AM26LV31EINSR is qualified at MSL1 260C

Qual Device AM26LV31INSR is qualified at MSL1 260C

Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable

The following are equivalent HTOL options based on an activation energy of 0.7eV : 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours

• The following are equivalent HTSL options based on an activation energy of 0.7eV : 150C/1k Hours, and 170C/420 Hours

• The following are equivalent Temp Cycle options per JESD47 : -55C/125C/700 Cycles and -65C/150C/500 Cycles

Quality and Environmental data is available at TI's external Web site: http://www.ti.com/

TI Qualification ID: R-CHG-2206-017

Qualification Results

Data Displayed as: Number of lots / Total sample size / Total failed

Туре	#	Test Name	Condition	Duration	Qual Device: <u>AM26LV31EIRGYR</u>	QBS Reference (Package): <u>TS3A5017QRGYRQ1</u>	QBS Reference (Process): TPS59632QRHBRQ1	QBS Reference (Product): AM26LV31EIDR
HAST	A2	Biased HAST	130C/85%RH	96 Hours	-	3/231/0	-	-
UHAST	A3	Autoclave	121C/15psig	96 Hours	-	3/231/0	-	-
TC	A4	Temperature Cycle	-65C/150C	500 Cycles	-	3/231/0	-	-
HTSL	A6	High Temperature Storage Life	150C	1000 Hours	-	3/135/0	-	-
WBS	C1	Ball Shear	76 balls, 3 units min	Wires	1/76/0	-	-	1/76/0
WBP	C2	Bond Pull	76 Wires, 3 units min	Wires	1/76/0	-	-	1/76/0
SD	C3	PB Solderability	Precondition w.155C Dry Bake (4 hrs +/- 15 minutes)	-	-	1/15/0	-	_
SD	C3	PB-Free Solderability	Precondition w.155C Dry Bake (4 hrs +/- 15 minutes)	-	-	1/15/0	-	-

Туре	#	Test Name	Condition	Duration	Qual Device: <u>AM26LV31EIRGYR</u>	QBS Reference (Package): <u>TS3A5017QRGYRQ1</u>	QBS Reference (Process): <u>TPS59632QRHBRQ1</u>	QBS Reference (Product): <u>AM26LV31EIDR</u>
ESD	E2	ESD CDM	-	250 Volts	1/3/0	-	-	-
ESD	E2	ESD HBM (Bus Pins)	-	15000 Volts	-	-	-	1/3/0
ESD	E2	ESD HBM	-	2000 Volts	-	-	-	1/3/0
LU	E4	Latch-Up	Per JESD78	-	-	-	-	1/6/0
CHAR	E5	Electrical Characterization	Per Datasheet Parameters	-	1/30/0	-	-	1/30/0

• QBS: Qual By Similarity

Qual Device AM26LV31EIRGYR is qualified at MSL2 260C

· Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable

• The following are equivalent HTOL options based on an activation energy of 0.7eV : 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours

The following are equivalent HTSL options based on an activation energy of 0.7eV : 150C/1k Hours, and 170C/420 Hours

The following are equivalent Temp Cycle options per JESD47 : -55C/125C/700 Cycles and -65C/150C/500 Cycles

Quality and Environmental data is available at TI's external Web site: http://www.ti.com/

TI Qualification ID: R-CHG-2205-046

Qualification Results

Data Displayed as: Number of lots / Total sample size / Total failed

Туре	#	Test Name	Condition	Duration	Qual Device: <u>AM26LV31EIPWR</u>	QBS Reference (Product): <u>AM26LV31EINSR</u>	QBS Reference (Package, Process): <u>TCA6416PW</u>
HAST	A2	Biased HAST	130C/85%RH	96 Hours	-	-	3/231/0
UHAST	A3	Autoclave	121C/15psig	96 Hours	-	-	3/231/0
TC	A4	Temperature Cycle	-65C/150C	500 Cycles	-	-	3/231/0
HTSL	A6	High Temperature Storage Life	150C	1000 Hours	-	-	3/231/0
HTOL	B1	Life Test	125C	1000 Hours	-	-	3/231/0
WBS	C1	Ball Shear	76 balls, 3 units min	Wires	1/76/0	-	-
WBP	C2	Bond Pull	76 Wires, 3 units min	Wires	1/76/0	-	-
ESD	E2	ESD CDM	-	1000 Volts	1/3/0	1/3/0	-
ESD	E2	ESD CDM	-	250 Volts	-	-	-
ESD	E2	ESD HBM	-	1000 Volts	-	1/3/0	-
ESD	E2	ESD HBM (Bus Pins)	-	15000 Volts	1/3/0	1/3/0	-
ESD	E2	ESD HBM	-	2000 Volts	1/3/0	-	-
LU	E4	Latch-Up	Per JESD78	-	-	-	1/6/0

PCN# 20240429005.1

Туре	#	Test Name	Condition	Duration	Qual Device: <u>AM26LV31EIPWR</u>	QBS Reference (Product): <u>AM26LV31EINSR</u>	QBS Reference (Package, Process): <u>TCA6416PW</u>
CHAR	E5	Electrical Characterization	Per Datasheet Parameters	-	1/30/0	1/30/0	1/30/0

• QBS: Qual By Similarity

- Qual Device AM26LV31EIPWR is qualified at MSL1 260C
- Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable
- The following are equivalent HTOL options based on an activation energy of 0.7eV : 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours
- The following are equivalent HTSL options based on an activation energy of 0.7eV : 150C/1k Hours, and 170C/420 Hours
- The following are equivalent Temp Cycle options per JESD47 : -55C/125C/700 Cycles and -65C/150C/500 Cycles

Quality and Environmental data is available at TI's external Web site: http://www.ti.com/

TI Qualification ID: R-CHG-2205-044

Qualification Results

Data Displayed as: Number of lots / Total sample size / Total failed

Туре	#	Test Name	Condition	Duration	Qual Device: <u>SN65LBC172A16DWR</u>	QBS Reference (Package): <u>TSS721AD</u>	QBS Reference (Product, Package): <u>SN65LBC175DWR</u>	QBS Reference (Product): <u>SN65LBC172ADWR</u>
тс	A4	Temperature Cycle	-65C/150C	500 Cycles	-	3/231/0	-	-
WBS	C1	Ball Shear	76 balls, 3 units min	Wires	1/76/0	-	1/76/0	1/76/0
WBP	C2	Bond Pull	76 Wires, 3 units min	Wires	1/76/0	-	1/76/0	1/76/0
ESD	E2	ESD CDM	-	1000 Volts	1/3/0	-	-	1/3/0
ESD	E2	ESD HBM (Bus Pins)	-	12000 Volts	-	-	-	1/3/0
ESD	E2	ESD HBM	-	5000 Volts	-	-	-	1/3/0
LU	E4	Latch-Up	Per JESD78	-	-	-	-	1/3/0
CHAR	E5	Electrical Characterization	Per Datasheet Parameters	-	1/30/0	-	-	1/30/0

QBS: Qual By Similarity

Qual Device SN65LBC172A16DWR is qualified at MSL1 260C

Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable

• The following are equivalent HTOL options based on an activation energy of 0.7eV : 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours

• The following are equivalent HTSL options based on an activation energy of 0.7eV : 150C/1k Hours, and 170C/420 Hours

• The following are equivalent Temp Cycle options per JESD47 : -55C/125C/700 Cycles and -65C/150C/500 Cycles

Quality and Environmental data is available at TI's external Web site: http://www.ti.com/

TI Qualification ID: R-CHG-2205-048

Qualification Results

Data Displayed as: Number of lots / Total sample size / Total failed

Туре	#	Test Name	Condition	Duration	Qual Device: <u>AM26LV31EIDR</u>	QBS Reference: <u>TLV9062ID</u>	QBS Reference: <u>TCA9546ADR</u>	QBS Reference: <u>TL494IDR</u>
HAST	A2	Biased HAST	130C/85%RH	96 Hours	-	3/231/0	-	3/231/0
UHAST	A3	Autoclave	121C/15psig	96 Hours	-	-	3/231/0	-
UHAST	A3	Unbiased HAST	130C	96 Hours	-	3/231/0	-	-
TC	A4	Temperature Cycle	-65/150C	500 Cycles	-	3/231/0	3/231/0	-
HTSL	A6	High Temperature Storage Life	170C	420 Hours	-	3/231/0	3/231/0	-
HTOL	B1	Life Test	150C	300 Hours	-	3/231/0	-	-
ELFR	B2	Early Life Failure Rate	125C	48 Hours	-	3/2400/1 ¹	-	-
WBS	C1	Ball Shear	76 balls, 3 units min	Wires	1/76/0	-	-	-
WBP	C2	Bond Pull	76 Wires, 3 units min	Wires	1/76/0	-	-	-
SD	C3	PB-Free Solderability	8 Hours Steam Age	-	-	-	3/66/0	-
SD	C3	PB-Free Solderability	Precondition w.155C Dry Bake (4 hrs +/- 15 minutes); PB-Free Solder;	-	-	3/66/0	-	-
ESD	E2	ESD CDM	-	1000 Volts	1/3/0	-	-	-
ESD	E2	ESD CDM	-	250 Volts	-	3/9/0	-	-
ESD	E2	ESD HBM	-	1000 Volts	-	3/9/0	-	-
ESD	E2	ESD HBM	-	15000 Volts	1/3/0	-	-	-
ESD	E2	ESD HBM	-	2000 Volts	1/3/0	-	-	-
LU	E4	Latch-Up	Per JESD78	-	1/3/0	3/18/0	-	-
CHAR	E5	Electrical Characterization	Min, Typ, Max Temp	-	1/30/0	3/90/0	-	-
CHAR	E5	Electrical Characterization	Per Datasheet Parameters	-	1/30/0	3/90/0	-	-

· QBS: Qual By Similarity

Qual Device AM26LV31EIDR is qualified at MSL1 260C

Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable

The following are equivalent HTOL options based on an activation energy of 0.7eV : 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours

The following are equivalent HTSL options based on an activation energy of 0.7eV : 150C/1k Hours, and 170C/420 Hours

The following are equivalent Temp Cycle options per JESD47 : -55C/125C/700 Cycles and -65C/150C/500 Cycles

Quality and Environmental data is available at TI's external Web site: http://www.ti.com/

Green/Pb-free Status:

Qualified Pb-Free(SMT) and Green

TI Qualification ID: R-CHG-2205-047

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